CMOS 8-Bit Microcontroller

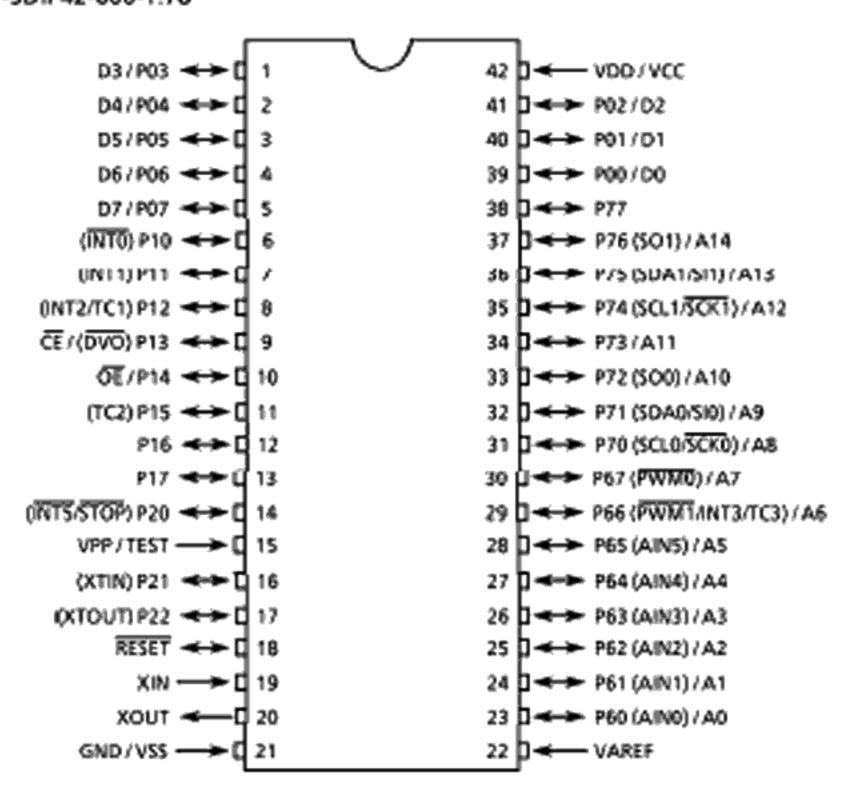
TMP87PM43N

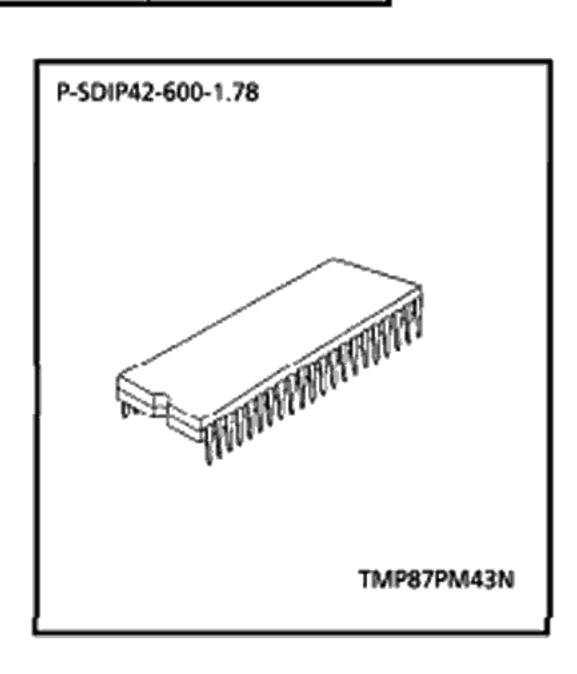
The 87PM43 is a One-Time PROM microcontroller with low-power 256K bits (a 32 Kbytes program memory) electrically programmable read only memory for the 87CK43/M43 system evaluation. The 87PM43 is pin compatible with the 87CK43/M43. The operations possible with the 87CK43/M43 can be performed by writing programs to PROM. The 87PM43 can write and verify in the same way as the TC57256AD using an adaptor socket BM1163 and an EPROM programmer.

Part No.	OTP RAM Package		Adaptor socket	
TMP87PM43N	32 Kbytes	1 Kbytes	P-SDIP42-600-1.78	BM1163

Pin Assignments (Top View)

P-SDIP42-600-1.78





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Pin Function

The 87PM43 has two modes: MCU and PROM.

(1) MCU mode
In this mode, the 87PM43 is pin compatible with the 87CK43/M43 (fix the TEST pin at low level).

(2) PROM mode

Pin Name (PROM mode)	Input/Output	Functions	Pin Name (MCU mode)				
A14 to A8	4	DDONG and done of the control	P76 to P70				
A7 to A0	Input	PROM address inputs	P67 to P60				
D7 to D0	I/O	PROM data input/outputs	P07 to P00				
CE		Chip enable signal input (active low)	P13				
<u>O</u> E	Input	Output enable signal input (active low)	P14				
VPP		+ 12.5 V / 5 V (Program supply voltage)	TEST				
vcc	Power supply	+5V	VDD				
GND		ov	VSS				
P11 P21 P77		PROM mode setting pin. Be fixed at high level.					
P12, P10	I/O	** *** *** *** *** *** *** ** ** ** **					
P17 to P15		PPOM mode catting pip. Po fixed at level and					
P22, P20		PROM mode setting pin. Be fixed at low level.					
RESET							
XIN	Input	Connect an 8 MHz oscillator to stabilize the internal state.					
хоит	Output						
VAREF	Power supply	0 V (GND)					

OPERATIONAL DESCRIPTION

The following explains the 87PM43 hardware configuration and operation. The configuration and functions of the 87PM43 are the same as those of the 87CK43/M43, except in that a one-time PROM is used instead of an on-chip mask ROM.

The 87PM43 is placed in the single-clock mode during reset. To use the dual-clock mode, the low-frequency oscillator should be turned on by executing [SET (SYSCR2). XTEN] instruction at the beginning of the program.

OPERATING MODE

The 87PM43 has two modes: MCU and PROM.

1.1 MCU Mode

The MCU mode is activated by fixing the TEST / VPP pin at low level.

In the MCU mode, operation is the same as with the 87CK43/M43 (the TEST / VPP pin cannot be used open because it has no built-in pull-down resistance).

1.1.1 Program Memory

The 87PM43 has a 32 Kbytes (addresses 8000_H to FFF_H in the MCU mode, addresses 0000_H to $7FFF_H$ in the PROM mode) of program memory (OTP).

When the 87PM43 is used as a system evaluation of the 87CK43/M43, the data is written to the program storage area shown in Figure 1-1.

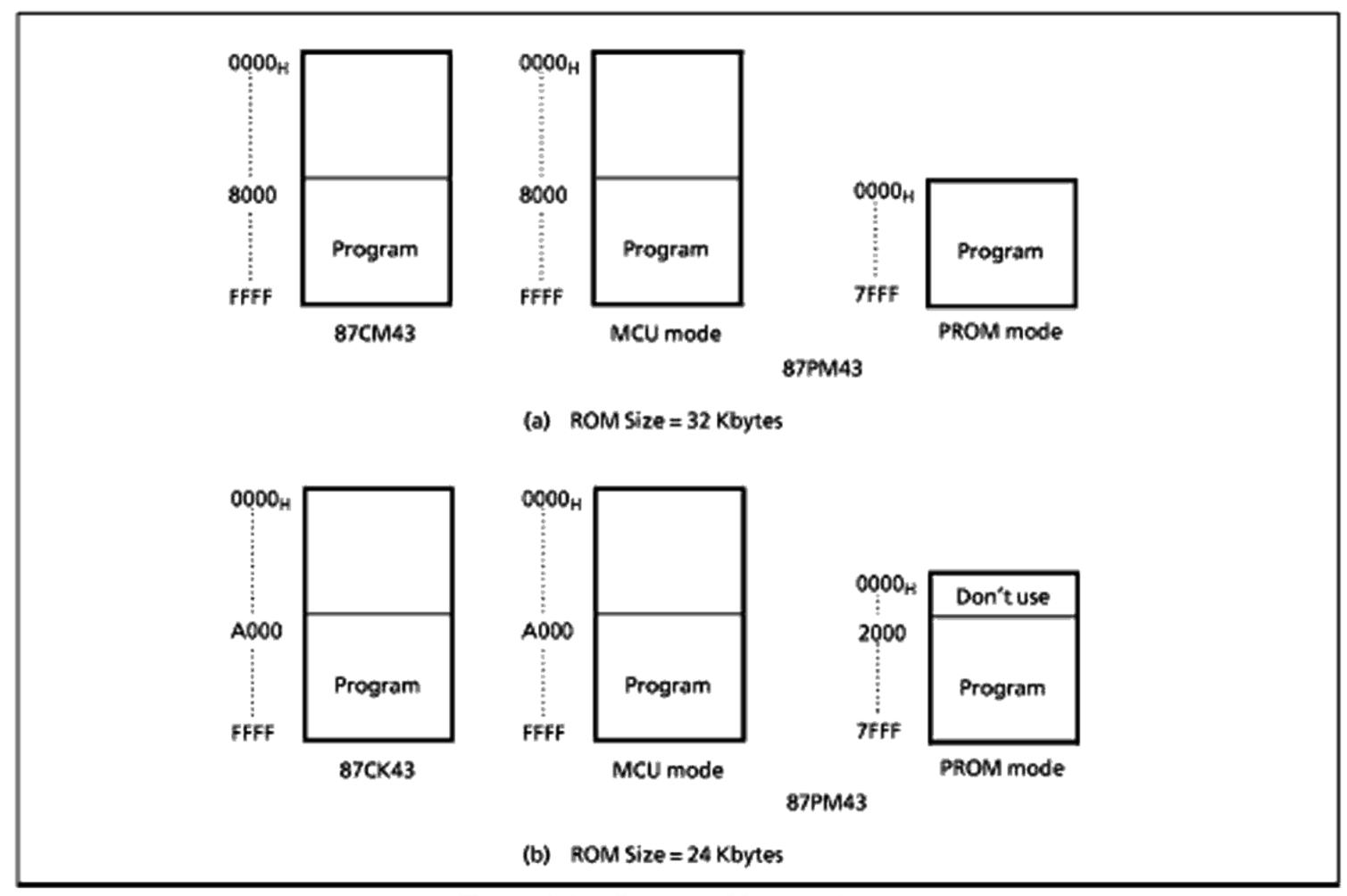


Figure 1-1. Program Memory Area

Note: Either write the data FF_H to the unused area or set the PROM programmer to access only the program storage area.

Electrical Characteristics

Absolute Maximum Ratings (V_{SS} = 0 V)

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	V _{DD}		- 0.3 to 6.5	٧
Program Voltage	V_{pp}	TEST/VPP	- 0.3 to 13.0	٧
Input Voltage	ViN		- 0.3 to V _{DD} + 0.3	٧
Output Voltage	V _{OUT1}	Ports P0, P1, P21, P22, P60 to P65, RESET, XOUT	- 0.3 to V _{DD} + 0.3	v
	V _{OUT2}	Ports P20, P66, P67, P7	- 0.3 to V _{DD} + 0.3	ľ
Output Current (Per 1 pin)	I _{OUT1}	Ports P0, P1, P2, P6, P7	3.2	mA
Output Current (Total)	ΣI _{OUT1}	Ports P0, P1, P2, P6, P7	120	mΑ
Power Dissipation [Topr = 70°C]	PD		600	mW
Soldering Temperature (time)	Tsld		260 (10s)	°C
Storage Temperature	Tstg		- 55 to 125	°C
Operating Temperature	Topr		- 30 to 70	°C

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Recommended Operating Conditions

 $(V_{SS} = 0 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$

Parameter	Symbol	Pins	-	Conditions		Max	Unit
			4	NORMAL1, 2 mode	4.5		
			fc=8MHz	IDLE1, 2 mode	4.5		
Supply Voltage	V _{DD}		fs =	SLOW mode	2.7	5.5	v
			32.768 kHz	SLEEP mode	2.7		
				STOP mode	2.0		
	V _{IH1}	Except hysteresis input	V _{DD} ≥4.5 V V _{DO} <4.5 V		V _{DD} × 0.70		
Input High Voltage	V _{IH2}	Hysteresis input			V _{DD} × 0.75	V _{DD}	v
	V _{IH3}				V _{DD} × 0.90		
	V _{IL1}	Except hysteresis input	,			V _{DD} × 0.30	
Input Low Voltage	V _{IL2}	Hysteresis input]	_{DD} ≥ 4.5 V	0	V _{DO} × 0.25	v
	V _{IL3}		V	V _{DD} <4.5 V		V _{DO} x 0.10	
Clark Francisco	fc	XIN, XOUT	V _{DD}	= 4.5 to 5.5 V	2.0	8.0	MHz
Clock Frequency	fs	XTIN, XTOUT	V _{DD}	= 2.7 to 5.5 V	30.0	34.0	kHz

Note 1: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

Note 2: fc: The condition of power supply voltage is limited to NORMAL1, NORMAL2, IDLE1, and IDLE2 mode.

D.C. Characteristics

 $(V_{SS} = 0 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$

Parameter	Symbol	Pins	Conditions	Min	Тур.	Max	Unit
Hysteresis Voltage	V _{HŞ}	Hysteresis inputs		-	0.9	-	٧
	l _{IN1}	TEST					
Input Current	I _{IN2}	Open drain ports, Tri-state ports	V _{DD} = 5.5 V V _{IN} = 5.5 V / 0 V	-	-	±2	μA
	I _{IN3}	RESET, STOP	1 N - 3 N -				
Input Resistance	R _{IN2}	RESET		100	220	450	kΩ
Output Leakage Current	ILO	Sink open drain ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	1	-	2	μΑ
Output High Voltage	V _{OH2}	Tri-state ports	$V_{DD} = 4.5 \text{ V, } I_{OH} = -0.7 \text{ mA}$	4.1	-	-	ν
Output Low Voltage	VOL	Except XOUT	$V_{DD} = 4.5 \text{ V}, I_{OL} = 1.6 \text{ mA}$	-	-	0.4	٧
Supply Current in NORMAL 1, 2 modes			V _{DD} = 5.5 V fc = 8 MHz	1	12	18	
Supply Current in IDLE 1, 2 modes			fs = 32.768 kHz V _{IN} = 5.3 V / 0.2 V	-	4.5	6	mA
Supply Current in SLOW mode	IDD		V _{DD} = 3.0 V	-	30	60	
Supply Current in SLEEP mode			fs = 32.768 kHz V _{IN} = 2.8 V / 0.2 V	1	15	30	μA
Supply Current in STOP mode			V _{DD} = 5.5 V V _{IN} = 5.3 V / 0.2 V	-	0.5	10	μА

Note 1: Typical values show those at Topr = 25°C, V_{DD} = 5 V.

Note 2: Input Current I_{IN1,I_{IN3}; The current through resistor is not included, when the input register (pull-up or pull-down) is contained.}

A / D Conversion Characteristics

 $(V_{SS} = 0 \text{ V}, V_{DO} = 4.5 \text{ to } 5.5 \text{ V}, Topr = -30 \text{ to } 70^{\circ}\text{C})$

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Analog Reference Voltage	VAREF	V _{DD} ≥4.5 V, V _{SS} = 0 V	V _{DD} _ 1.5	-	V _{DD}	٧
Analog Reference Voltage Range	$_{\Delta}V_{AREF}$		3.0	-	-	٧
Analog Input Voltage Range	V _{AIN}		V _{SS}	-	VAREF	٧
Analog Supply Current	I _{REF}		-	0.5	1.0	mA
Nonlinearity Error			-	-	± 1	
Zero Point Error		V _{DD} = 5.0 V, V _{SS} = 0.000 V	-	-	± 1	
Full Scale Error		V _{AREF} = 5.000 V	-	-	±1	L\$B
Total Error			_	-	±2	

Note 1: $\Delta V_{AREF} = V_{AREF} - V_{SS}$

Note 2: Quantizing error is not contained in those errors.

A.C. Characteristics

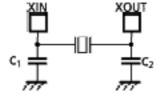
$$(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$$

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Machine Cycle Time		In NORMAL1, 2 modes	0.5		- 10	
	Ι.	In IDLE1, 2 modes	0.5	-	10	
	t _{cy}	In SLOW mode	117.6		100.0	μ\$
		In SLEEP mode	117.6	-	133.3	
High Level Clock Pulse Width	two	For external clock operation				
Low Level Clock Pulse Width	twcL	(XIN input), fc = 8 MHz	50	-	-	ns
High Level Clock Pulse Width	twsH	For external clock operation	-4.7			
Low Level Clock Pulse Width	twsL	(XTIN input), fs = 32.768 kHz	14.7	-	-	μS

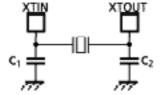
Recommended Oscillating Conditions

$$(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, Topr = -30 \text{ to } 70^{\circ}\text{C})$$

		Oscillation	B		Recommended Constant		
Parameter Oscillator		Frequency	Recommen	nded Oscillator	C ₁	C ₂	
High-frequency		8 MHz	KYOCERA	KBR8.0M			
	Ceramic Resonator		KYOCERA	KBR4.0MS	30 pF	30 pF	
		4 MHz	MURATA	CSA4.00MG			
Oscillation		8 MHz	тоуосом	210B 8.0000			
	Crystal Oscillator	4 MHz	тоуосом	204B 4.0000	20 pF	20 pF	
Low-frequency Oscillation	Crystal Oscillator	32.768 kHz	NDK	MX-38T	15 pF	15 pF	



(1) High-frequency Oscillation



(3) Low-frequency Oscillation

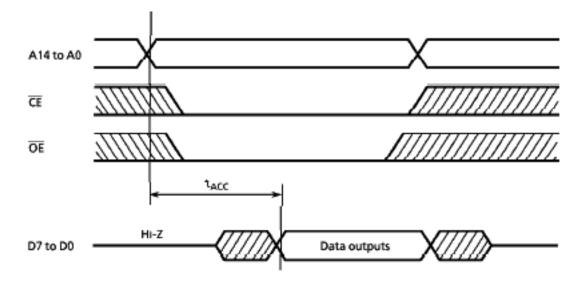
Note: An electrical shield by metal shield plate on the surface of the IC package should be recommendable in order to prevent the device from the high electric fieldstress applied from CRT (Cathode Ray Tube) for continuous reliable operation.

D.C./A.C. Characteristics (PROM mode) (V_{SS} = 0 V)

(1) READ OPERATION (Topr = 0 to 70°C)

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Input High Voltage	V _{IH4}		V _{CC} ×0.7	-	Vcc	٧
Input Low Voltage	V _{IL4}		0	-	V _{CC} × 0.12	٧
Power Supply Voltage	Vcc		4.75		6.0	v
Program Power Supply Voltage	Vpp		4.75	_	6.0	*
Address Access Time	t _{ACC}	V _{CC} = 5.0 ± 0.25 V	-	1.5tcyc + 300	-	ns

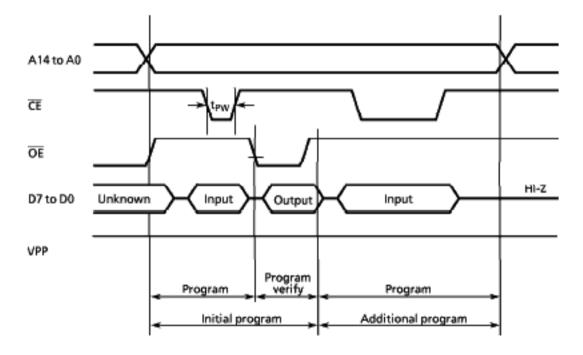
Note: tcyc = 500 ns at 8 MHz



Timing Waveforms of Read Operation

(2) High-Speed Programming Operation (High-Speed Programming Mode- I) (Topr = 25 ± 5°C)

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Input High Voltage	V _{IH4}		V _{CC} × 0.7	-	Vcc	٧
Input Low Voltage	V _{IL4}		0	_	V _{CC} × 0.12	٧
Power Supply Voltage	vcc		5.75	6.0	6.25	٧
Program Power Supply Voltage	V _{PP}		12.0	12.5	13.0	٧
Initial Program Pulse Width	t _{PW}	V _{CC} = 6.0 V ± 0.25 V V _{PP} = 12.5 ± 0.25 V	0.95	1.0	1.05	ms



Timing Waveforms of Programming Operation

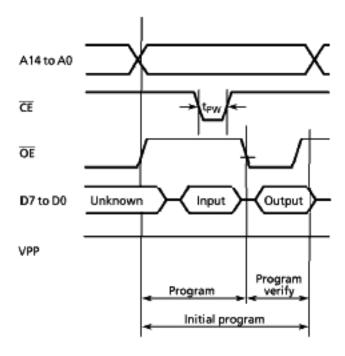
Note 1: When V_{cc} power supply is turned on or after, V_{pp} must be increased. When V_{cc} power supply is turned off or before, V_{pp} must be decreased.

Note 2: The device must not be set to the EPROM programmer or picked up from it under applying the program voltage (12.5 V ± 0.5 V) to the V_{pp} pin as the device is damaged.

Note 3: Be sure to execute the recommended programing mode with the recommended programing adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.

(3) High-Speed Programming Operation (High-Speed program mode-II) (Topr = 25 ± 5°C)

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Input High Voltage	V _{IH4}		V _{CC} × 0.7	-	Vcc	٧
Input Low Voltage	V _{IL4}		0	-	V _{CC} × 0.12	>
Supply Voltage	Vcc		6.00	6.25	6.50	٧
Program Supply Voltage	Vpp		12.50	12.75	13.0	٧
Initial Program Pulse Width	tpw	V _{CC} = 6.25 V ± 0.25 V, V _{PP} = 12.75 ± 0.25 V	0.095	0.1	0.105	ms



- Note 1: When V_{cc} power supply is turned on or after, V_{pp} must be increased. When V_{cc} power supply is turned off or before, V_{pp} must be decreased.
- Note 2: The device must not be set to the EPROM programmer or picked up from it under applying the program voltage (12.75 V \pm 0.25 V) to the V_{pp} pin as the device is damaged.
- Note 3: Be sure to execute the recommended programing mode with the recommended programing adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.